



# Theory of transversal light forces in semiconductors

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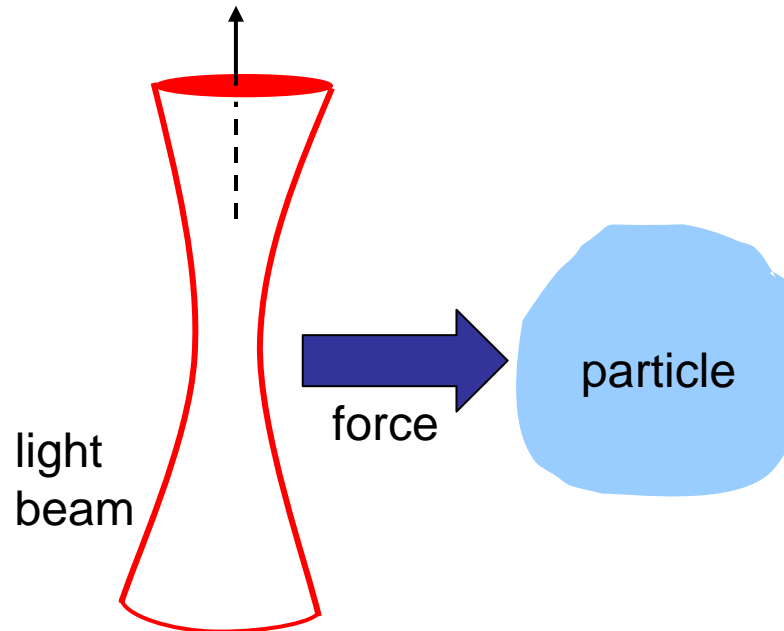
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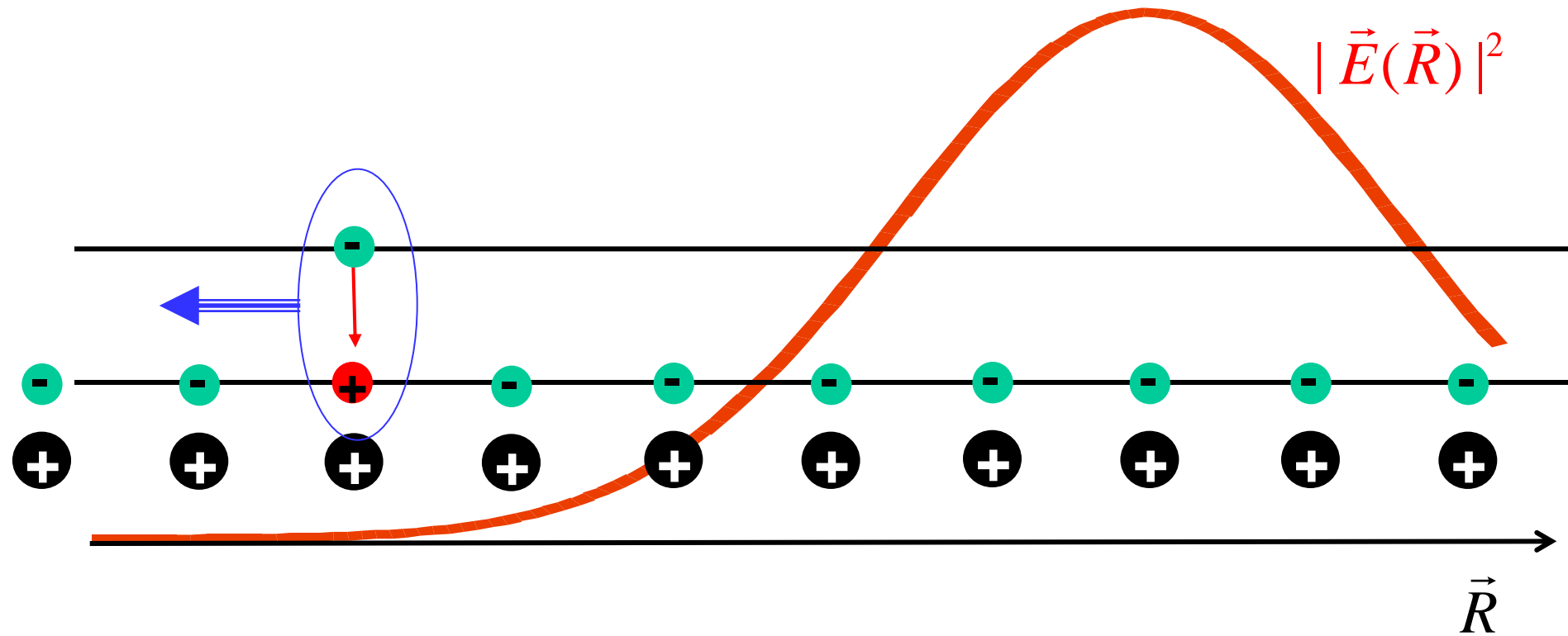
## Light forces and optical tweezers



- ◆ Transversal light force (light gradient force) verified for atoms, molecules, bacteria, dielectric spheres *etc.*
- ◆ Example: controlled transport of gaseous Bose-Einstein condensate over 44 cm (Ketterle group, PRL 88, 020401 (2002))



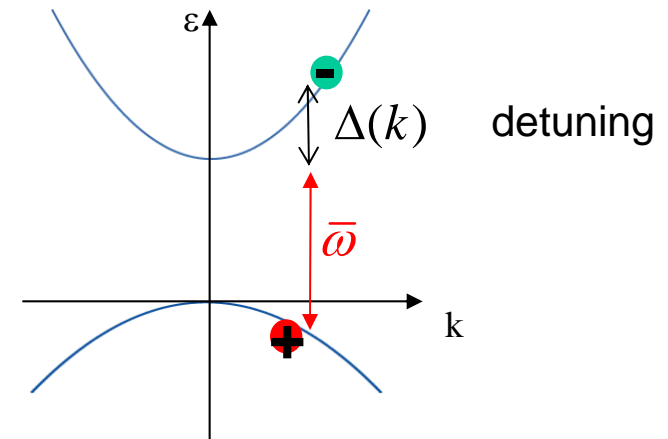
## Semiconductor: Electronic Excitation Moving





## Transversal Force on Electrons and Holes

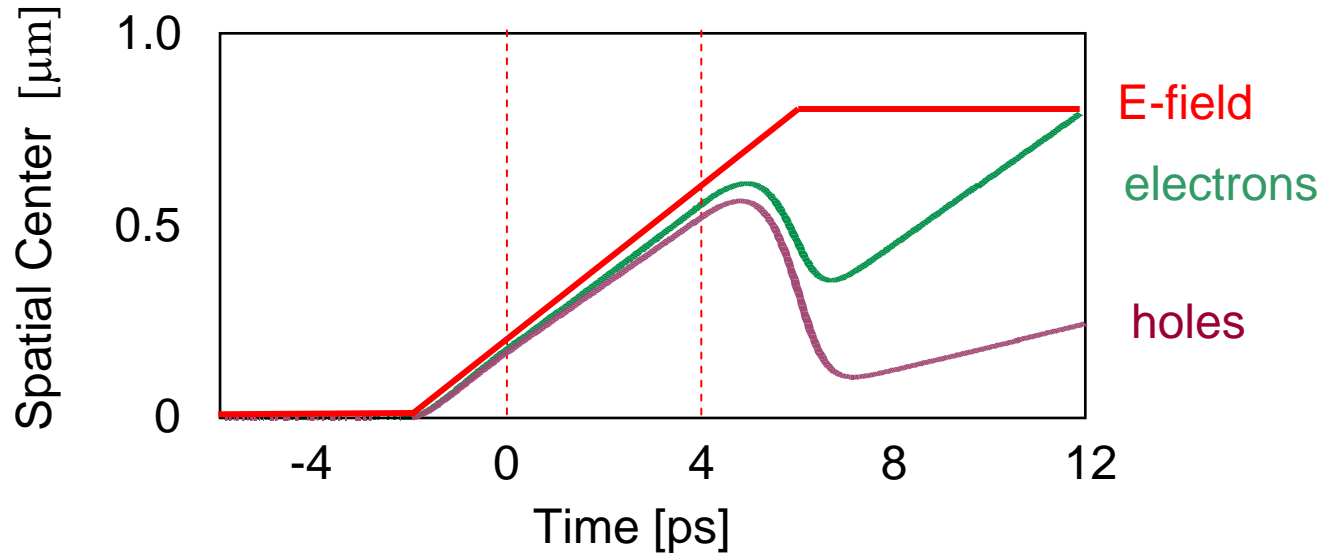
$$\vec{F}_{transv}(\vec{R}) = -\hbar \nabla_{\vec{R}} \left( \left| \vec{\mu} \cdot \vec{E}(\vec{R}) \right|^2 \right) \frac{\Delta(\vec{K})}{\gamma^2 + \Delta(\vec{K})^2}$$



- ◆ Same structural form as for atoms
- ◆ Different sign than for atoms
- ◆ Practically, restricted to **repulsive force** (since E-field needs to be red detuned,  $\Delta(K) > 0$ )



## Spatial center of carrier density distribution



- Spatial displacement after E-field gone
- Non-zero velocities after E-field gone